MRON

Photomicrosensor (Actuator) E-SA1 13

Dimensions

Note: All units are in millimeters unless otherwise indicated.



Internal Circuit



Unless otherwise specified, the tolerances are as shown below.

A ()			Dimensions	Tolerance	
S 0-			3 mm max.	±0.3	
Terminal No.	Name		$3 < mm \le 6$	±0.375	
Α	Anode	1	6 < mm ≤ 10	±0.45	
К	Cathode		10 < mm ≤ 18	±0.55	
С	Collector		18 < mm ≤ 30	±0.65	
E	Emitter				

Features

- Model has an actuator.
- Low operating force (0.15 N (15 gf)).
- · Connects to circuits with ease.

■ Absolute Maximum Ratings (Ta = 25°C		Absolute	Maximum	Ratings	(Ta = 25°C))
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	Item	Symbol	Rated value
Emitter	Forward current	I _F	50 mA (see note 1)
	Pulse forward cur- rent	I _{FP}	1 A (see note 2)
	Reverse voltage	V _R	4 V
	Collector–Emitter voltage	V _{CEO}	30 V
Detector	Emitter–Collector voltage	V _{ECO}	5 V
	Collector current	I _C	20 mA
	Collector dissipa- tion	P _c	100 mW (see note 1)
Ambient tem-	Operating	Topr	–25°C to 70°C
perature	Storage	Tstg	–40°C to 85°C
Soldering temperature		Tsol	260°C (see note 3)

Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

- 2. The pulse width is 10 μs maximum with a frequency of 100 Hz.
- 3. Complete soldering within 10 seconds.

■ Electrical and Optical Characteristics (Ta = 25°C)

	Item	Symbol	Value	Condition
Emitter	Forward voltage	V _F	1.2 V typ., 1.5 V max.	I _F = 30 mA
	Reverse current	I _R	0.01 μA typ., 10 μA max.	$V_{R} = 4 V$
	Peak emission wavelength	λ_{P}	940 nm typ.	I _F = 20 mA
Detector	Light current	I _L	0.5 mA min.	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$ at free position (FP)
	Dark current	I _D	2 nA typ., 200 nA max.	V _{CE} = 10 V, 0 <i>l</i> x
	Leakage current	I _{LEAK}	10 μA max.	$I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$ at operating position (OP)
	Collector–Emitter saturated voltage	V _{CE} (sat)	0.15 V typ., 0.4 V max.	$I_{\rm F} = 20 \text{ mA}, I_{\rm L} = 0.1 \text{ mA}$
	Peak spectral sensitivity wavelength	λ_P	850 nm typ.	V _{CE} = 10 V
Rising tim	ne	tr		
Falling tim	ne	tf		

Mechanical Characteristics

•	Free position (FP):11.4±0.3 mmOperating position (OP):10.2 mm min.Total travel position (TTP):9.3 mm max.	
Operating force (see note 2)	0.15 N (15 gf) max.	
Mechanical life expectancy	500,000 operations min. (The actuator traveling from its FP to FP via TTP is regarded as one operation.)	

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Engineering Data

Forward Current vs. Collector **Dissipation Temperature Rating**



Light Current vs. Collector-Emitter Voltage Characteristics (Typical)



Sensing Position Characteristics (Typical)





0.6 0.8

0.4

1.6

I_F= 20 mA V_{CE} = 5 V

1.2

Forward voltage V_F (V)

Relative Light Current vs. Ambi-

ent Temperature Characteristics

1.4

Forward Current vs. Forward

Light Current vs. Forward Current Characteristics (Typical)



Dark Current vs. Ambient **Temperature Characteristics** (Typical)



(Typical) 120 110 100

з

20

10

° 0 0.2

Forward

